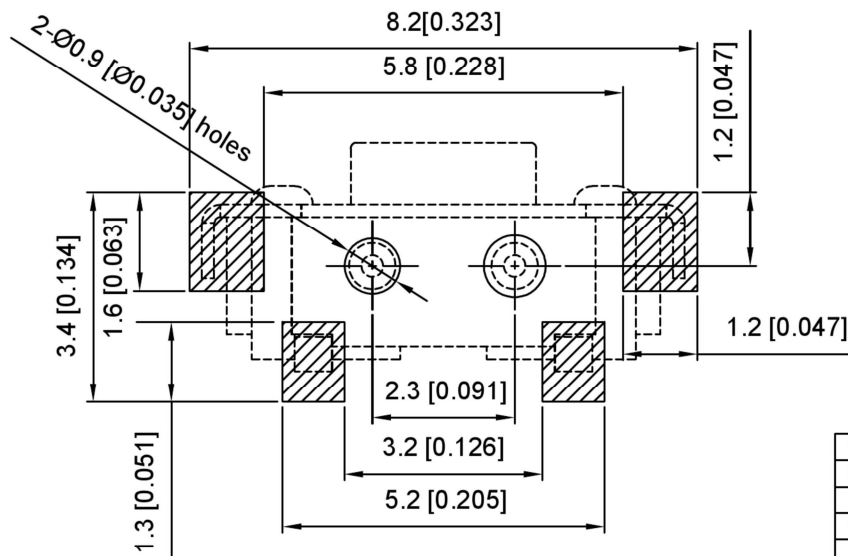
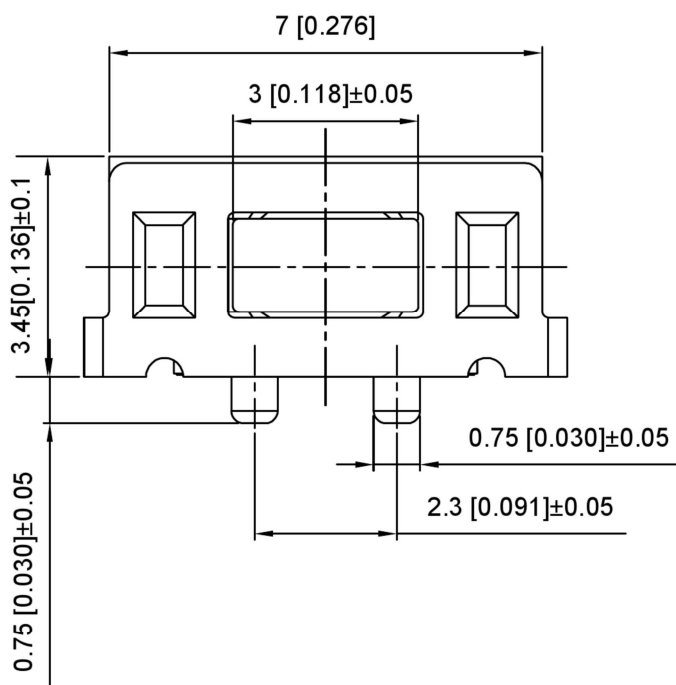
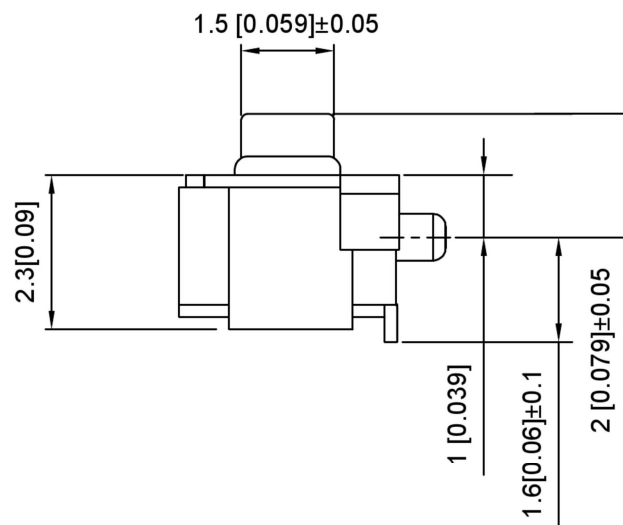
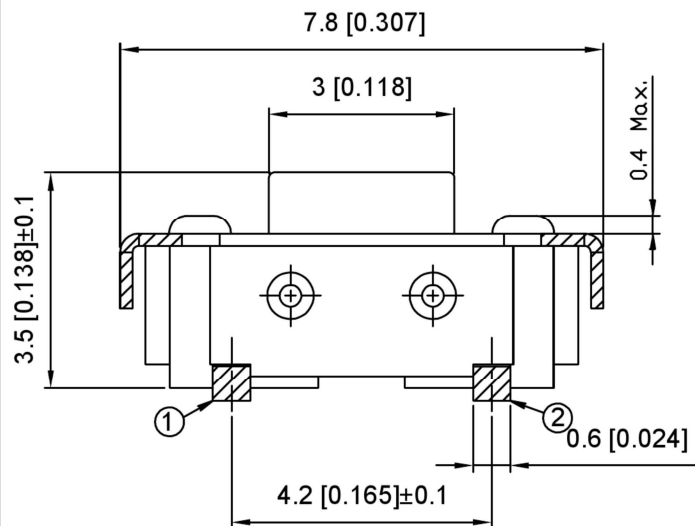
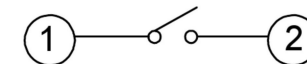




CIRCUIT DIAGRAM



SPECIFICATION

Contact Rating:	50mA, 12V DC
Contact Resistance:	100mΩ max
Insulation Resistance:	100MΩ min. 500V DC
Dielectric Strength:	250V AC/1 minute
Travel:	0.25mm
Operating Temp:	-25℃ ~ +70℃
Storage Temp:	-30℃ ~ +80℃

PAPT NO	TS-1101VS-X-X-A
Operating Force	A:100gf B:160gf C:260gf
Height	H:3.5
Fixed column	A:With B:without
Keystake	A:PA46 B:Silica gel

⑤	Terminal	—	2	Brass (0.30t)	ag Plated	—
④	Contact	—	1	F.ag/SUS	—	—
③	Base	—	1	PA46	—	—
②	Cover	—	1	Brass	Tin plated	—
①	Keystake	—	1	PA46	—	—
ITEM	PAPT NAMF	TER.NO	QTY	MATERIAL	FINISHING	REMAR

DSND		SCALE: N/A	MODEL TYPE:
DWN		VIEW:	TACT SWITCH
CHKD		UNIT: mm/in	PART NO.:
APPD		SIZE: A4	TS-1101VS-X-X-A
			DWG NO.:

				ANGULAR	±5°
				L ≤ 4	±0.2
				4 < L ≤ 16	±0.3
				16 < L ≤ 63	±0.4
				L > 63	±0.5
	DATE	REVISED	APPROVED	UNSPECIFIED TOLERANCES	



DONG GUAN XI BANG ELECTRONIC CO., LTD